FEATURES

- Peak efficiency up to 93.2% at 1.2V
- Integrated driver, control MOSFET, synchronous MOSFET and Schottky diode
- Input voltage (VIN) operating range up to 15V
- Output voltage range from 0.25V up to 3.3V
- Output current capability of 40A DC
- Operation up to 1.0MHz
- Integrated current sense amplifier
- VCC under voltage lockout
- Thermal flag
- Body-Braking® load transient support
- Diode-emulation high efficiency mode
- Compatible with 3.3V PWM logic and VCC tolerant
- Compliant with Intel DrMOS V4.0
- PCB footprint compatible with IR3550 and IR3551
- Efficient dual sided cooling
- Small 4mm x 6mm x 0.9mm PQFN package
- Lead free RoHS compliant package

APPLICATIONS

BASIC APPLICATION

- Voltage Regulators for CPUs, GPUs, and DDR memory arrays
- High current, low profile DC-DC converters

DESCRIPTION

The IR3553 integrated PowIRstage® is a synchronous buck gate driver co-packed with a control MOSFET and a synchronous MOSFET with integrated Schottky diode. It is optimized internally for PCB layout, heat transfer and driver/MOSFET timing. Custom designed gate driver and MOSFET combination enables higher efficiency at lower output voltages required by cutting edge CPU, GPU and DDR memory designs.

Up to 1.0MHz switching frequency enables high performance transient response, allowing miniaturization of output inductors, as well as input and output capacitors while maintaining industry leading efficiency. The IR3553's superior efficiency enables smallest size and lower solution cost. The IR3553 PCB footprint is compatible with the IR3550 (60A) and the IR3551 (50A).

Integrated current sense amplifier achieves superior current sense accuracy and signal to noise ratio vs. best-inclass controller based Inductor DCR sense methods.

The IR3553 incorporates the Body- Braking® feature which enables reduction of output capacitors. Synchronous diode emulation mode in the IR3553 removes the zero-current detection burden from the PWM controller and increases system light-load efficiency.

The IR3553 is optimized specifically for CPU core power delivery in server applications. The ability to meet the stringent requirements of the server market also makes the IR3553 ideally suited to powering GPU and DDR memory designs and other high current applications.

Figure 1: IR3553 Basic Application Circuit

Figure 2: Typical IR3553 Efficiency & Power Loss (See Note 2 on Page 8)

PINOUT DIAGRAM

Figure 3: IR3553 Pin Diagram, Top View

ORDERING INFORMATION

TYPICAL APPLICATION DIAGRAM

Figure 4: Application Circuit with Current Sense Amplifier

TYPICAL APPLICATION DIAGRAM (CONTINUED)

FUNCTIONAL BLOCK DIAGRAM

Figure 6: IR3553 Functional Block Diagram

PIN DESCRIPTIONS

ABSOLUTE MAXIMUM RATINGS

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied.

Note:

1. Maximum BOOST $-$ SW = 8V.

2. Maximum VIN $-$ SW = 25V.

3. All the maximum voltage ratings are referenced to PGND (Pins 12 and 13).

Note:

1. Thermal Resistance (θ_{1A}) is measured with the component mounted on a high effective thermal conductivity test board in free air. Refer to International Rectifier Application Note AN-994 for details.

ELECTRICAL SPECIFICATIONS

The electrical characteristics involve the spread of values guaranteed within the recommended operating conditions. Typical values represent the median values, which are related to 25°C.

RECOMMENDED OPERATING CONDITIONS FOR RELIABLE OPERATION WITH MARGIN

ELECTRICAL CHARACTERISTICS

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Notes

- 1. Guaranteed by design but not tested in production
- 2. V_{IN}=12V, V_{OUT}=1.2V, f_{SW} = 300kHz, L=210nH (0.2mΩ), VCC=6.8V, C_{IN}=47uF x 4, C_{OUT} =470uF x3, 400LFM airflow, no heat sink, 25°C ambient temperature, and 8-layer PCB of 3.7" (L) x 2.6" (W). PWM controller loss and inductor loss are not included.
- 3. V_{IN}=12V, V_{OUT}=1.2V, f_{SW} = 400kHz, L=150nH (0.29m Ω), VCC=7V, C_{IN}=47uF x 4, C_{OUT} =470uF x3, no airflow, no heat sink, 25°C ambient temperature, and 8-layer PCB of 3.7" (L) x 2.6" (W). PWM controller loss and inductor loss are not included.

TYPICAL OPERATING CHARACTERISTICS

Circuit of Figure 32, V_{IN}=12V, V_{OUT}=1.2V, f_{SW} = 400kHz, L=150nH (0.29m Ω), VCC=7V, T_{AMBIENT} = 25°C, no heat sink, no air flow, 8-layer PCB board of 3.7" (L) x 2.6" (W), no PWM controller loss, no inductor loss, unless specified otherwise.

Figure 10: Normalized Power Loss vs. Input Voltage

Figure 8: Typical IR3553 Power Loss

Figure 11: Normalized Power Loss vs. Output Voltage

Figure 12: Normalized Power Loss vs. Switching Frequency

TYPICAL OPERATING CHARACTERISTICS (CONTINUED)

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Circuit of Figure 32, V_{IN}=12V, V_{OUT}=1.2V, f_{SW} = 400kHz, L=150nH (0.29m Ω), VCC=7V, T_{AMBIENT} = 25°C, no heat sink, no air flow, 8-layer PCB board of 3.7" (L) x 2.6" (W), no PWM controller loss, no inductor loss, unless specified otherwise.

TYPICAL OPERATING CHARACTERISTICS (CONTINUED)

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Circuit of Figure 32, V_{IN}=12V, V_{OUT}=1.2V, f_{SW} = 400kHz, L=150nH (0.29m Ω), VCC=7V, T_{AMBIENT} = 25°C, no heat sink, no air flow, 8-layer PCB board of 3.7" (L) x 2.6" (W), no PWM controller loss, no inductor loss, unless specified otherwise.

TYPICAL OPERATING CHARACTERISTICS (CONTINUED)

Circuit of Figure 32, V_{IN}=12V, V_{OUT}=1.2V, f_{SW} = 400kHz, L=150nH (0.29m Ω), VCC=7V, T_{AMBIENT} = 25°C, no heat sink, no air flow, 8-layer PCB board of 3.7" (L) x 2.6" (W), no PWM controller loss, no inductor loss, unless specified otherwise.

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Figure 25: Diode Emulation Setup through BBRK# Input

Figure 28: Current Sense Amplifier Output, $I_{OUT} = 0A$

Figure 29: Current Sense Amplifier Output, I_{OUT} = 20A

Figure 30: Current Sense Amplifier Output, I_{OUT} = 20A, 300kHz

THEORY OF OPERATION

DESCRIPTION

The IR3553 PowIRstage® is a synchronous buck driver with co-packed MOSFETs with integrated Schottky diode, which provides system designers with ease of use and flexibility required in cutting edge CPU, GPU and DDR memory power delivery designs and other high-current low-profile applications.

The IR3553 is designed to work with a PWM controller. It incorporates a continuously self-calibrated current sense amplifier, optimized for use with inductor DCR sensing. The current sense amplifier provides signal gain and noise immunity, supplying multiphase systems with a superior design toolbox for programmed impedance designs.

The IR3553 provides a phase fault signal capable of detecting open or shorted MOSFETs, or an overtemperature condition in the vicinity of the power stage.

The IR3553 accepts an active low Body-Braking® input which disables both MOSFETs to enhance transient performance or provide a high impedance output.

The IR3553 provides diode emulation feature which avoids negative current in the synchronous MOSFET and improves light load efficiency.

The IR3553 PWM input is compatible with 3.3V logic signal and 7V tolerant. It accepts 3-level PWM input signals with tri-state.

PWM TRI-STATE INPUT

The IR3553 PWM accepts 3-level input signals. When PWM input is high, the synchronous MOSFET is turned off and the control MOSFET is turned on. When PWM input is low, control MOSFET is turned off and synchronous MOSFET is turned on. Figures 16-18 show the PWM input and the corresponding SW and GATEL output of the IR3553. If PWM pin is floated , the built-in resistors pull the PWM pin into a tri-state region centered around 1.65V.

When PWM input is in tri-state, two operation modes can be selected by controlling BBRK# input. If the BBRK# input is always high, the default operation mode is Body-Braking®, in which both MOSFETs will be turned off when the PWM input is in tri-state. If the BBRK# input has been pulled low for at least 20ns after the VCC passes its UVLO threshold during power up, the diode emulation mode is

set. PWM input in tri-state will activate a synchronous diode emulation feature allowing designers to maximize system efficiency at light loads without compromising transient performance.

BODY-BRAKING® MODE

International Rectifier's Body-Braking® is a operation mode in which two MOSFETs are turned off. When the synchronous MOSFET is off, the higher voltage across the Shottky diode in parallel helps discharging the inductor current faster, which reduces the output voltage overshoot. The Body-Braking® can be used either to enhance transient response of the converter after load release or to provide a high impedance output.

There are two ways to place the IR3553 in Body-Braking® mode, either controlling the BBRK# pin directly or through a PWM tri-state signal. Both control signals are usually from the PWM controller.

Pulling BBRK# low forces the IR3553 into Body-Braking® mode rapidly, which is usually used to enhance converter transient response after load release, as shown in Figure 19. Releasing BBRK# forces the IR3553 out of Body-Braking® mode quickly.

The BBRK# low turns off both MOSFETs and therefore can also be used to disable/enable a converter.

If the BBRK# input is always high, the Body-Braking® is activated when the PWM input enters the tri-state region, as shown in Figures 20 and 21. Comparing to pulling down the BBRK# pin directly, the Body-Braking® response to PWM tri-state signal is slower due to the hold-off time created by the PWM pin parasitic capacitor with the pullup and pull-down resistors of PWM pin. For better performance, no more than 100pF parasitic capacitive load should be present on the PWM line of IR3553.

SYNCHRONOUS DIODE EMULATION MODE

An additional feature of the IR3553 is the synchronous diode emulation mode. This function enables increased efficiency by preventing negative inductor current from flowing in the synchronous MOSFET.

As shown in Figure 22, when the PWM input enters the tristate region the control MOSFET is turned off first, and the synchronous MOSFET is initially turned on and then is turned off when the output current reaches zero. If the sensed output current does not reach zero within a set amount of time the gate driver will assume that the output is de-biased and turn off the synchronous MOSFET, allowing the switch node to float.

This is in contrast to the Body-Braking® mode shown in Figure 23, where GATEL follows PWM input. The Schottky diode in parallel with the synchronous MOSFET conducts for a longer period of time and therefore lowers the light load efficiency.

The zero current detection circuit in the IT3553 is independent of the current sense amplifier and therefore still functions even if the current sense amplifier is not used. As shown in Figure 6, an offset is added to the diode emulation comparator so that a slightly positive output current in the inductor and synchronous MOSFET is treated as zero current to accommodate propagation delays, preventing any negative current flowing in the synchronous MOSFET. This causes the Schottky diode in parallel with the synchronous MOSFET to conduct before the inductor current actually reaches zero, and the conduction time increases with inductance of the output inductor.

To set the IR3553 in diode emulation mode, the BBRK# pin must be toggled low at least once after the VCC passes its UVLO threshold during power up. One simple way is to use the internal BBRK# pull-up resistor (200k Ω typical) with an external capacitor from BBRK# pin to LGND, as shown in Figure 4. To ensure the diode emulation mode is properly set, the BBRK# voltage should be lower than 0.8V when the VCC voltage passes its UVLO threshold (3.3V minimum and 3.7V typical), as shown in Figure 24. A digital signal from the PWM controller can also be used to set the diode emulation mode. The BBRK# signal can either be pulled low for at least 20ns after the VCC passes its UVLO threshold, as shown in Figure 25, or be pulled low before VCC power up and then released after the VCC passes its UVLO threshold, as shown in Figure 26.

Once the diode emulation mode is set, it cannot be reset until the VCC power is recycled.

PHASE FAULT AND THERMAL FLAG OUTPUT

The phase fault circuit looks at the switch node with respect to ground to determine whether there is a defective MOSFET in the phase. The output of the phase fault signal is high during normal operation and is pulled low when there is a fault. Each driver monitors the MOSFET it drives. If the switch node is less than a certain voltage above ground when the PWM signal goes low or if the switch node is a certain voltage above ground when the PWM signal rises, this gives a fault signal. If there are a

Thermal flag circuit monitors the temperature of the IR3553. If the temperature goes above a threshold (160°C typical) the PHSFLT# pin is pulled low after a maximum delay of 100us.

The PHSFLT# pin can be pulled low by either the phase fault circuit or the thermal flag circuit. The phase fault signal could be used to turn off the AC/DC converter or blow a fuse to disconnect the DC/DC converter input from the supply.

If PHSFLT# is not used it can be floated or connected to LGND.

LOSSLESS AVERAGE INDUCTOR CURRENT SENSING

Inductor current can be sensed by connecting a series resistor and a capacitor network in parallel with the inductor and measuring the voltage across the capacitor, as shown in Figure 31.

Figure 31: Inductor current sensing

The equation of the current sensing network is as follows.

$$
v_{CS}(s) = v_L(s) \frac{1}{1 + sR_{CS}C_{CS}} = i_L(s)R_L \frac{1 + s\frac{L}{R_L}}{1 + sR_{CS}C_{CS}}
$$

$$
= i_L(s)R_L \text{ when } L/R_L = R_{CS}C_{CS}
$$

Usually the resistor R_{CS} and capacitor C_{CS} are chosen so that the time constant of R_{CS} and C_{CS} equals the inductor time

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constant, which is the inductance L over the inductor DCR (R_L). If the two time constants match, the voltage across C_{CS} is proportional to the current through L, and the sense circuit can be treated as if only a sense resistor with the value of R_L was used. The mismatch of the time constants does not affect the measurement of inductor DC current, but affects the AC component of the inductor current.

The advantage of sensing the inductor current versus high side or low side sensing is that actual output current being delivered to the load is obtained rather than peak or sampled information about the switch currents. The output voltage can be positioned to meet a load line based on real time information. This is the only sense method that can support a single cycle transient response. Other methods provide no information during either load increase (low side sensing) or load decrease (high side sensing).

CURRENT SENSE AMPLIFIER

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A high speed differential current sense amplifier is located in the IR3553, as shown in Figure 6. Its gain is nominally 32.5, and the inductor DCR increase with temperature is not compensated inside the IR3553. The current sense amplifier output IOUT is referenced to REFIN, which is usually connected to a reference voltage from the PWM controller. Figure 27 shows the differential voltage of $V(IOUT) - V(REFIN)$ versus the inductor current and reflects the inductor DCR increase with temperature at higher current.

The current sense amplifier can accept positive differential input up to 25mV and negative input up to -10mV before clipping. The output of the current sense amplifier is summed with the reference voltage REFIN and sent to the IOUT pin. The REFIN voltage is to ensure at light loads there is enough output range to accommodate the negative current ripple shown in Figure 28. In a multiphase converter, the IOUT pins of all the phases can be tied together through resistors, and the IOUT voltage represents the average current through all the inductors and is used by the controller for adaptive voltage positioning.

The input offset voltage is the primary source of error for the current signal. In order to obtain very accurate current signal, the current sense amplifier continuously calibrates itself, and the input offset of this amplifier is within +/- 450uV. This calibration algorithm can create a small ripple on IOUT with a frequency of fsw/128.

If the IR3553 current sense amplifier is required, connect its output IOUT and the reference voltage REFIN to the PWM controller and connect the inductor sense circuit as shown in Figure 4. If the current sense amplifier is not needed, tie CSIN+, CSIN- and REFIN pins to LGND and float IOUT pin, as shown in Figure 5.

DESIGN PROCEDURES

POWER LOSS CALCULATION

The single-phase IR3553 efficiency and power loss measurement circuit is shown in Figure 32.

Figure 32: IR3553 Power Loss Measurement

The IR3553 power loss is determined by,

$$
P_{\text{LOSS}} = V_{\text{IN}} \times I_{\text{IN}} + V_{\text{CC}} \times I_{\text{VCC}} - V_{\text{SW}} \times I_{\text{OUT}}
$$

Where both MOSFET loss and the driver loss are included, but the PWM controller and the inductor losses are not.

Figure 7 shows the measured single-phase IR3553 efficiency under the default test conditions, V_{IN} =12V, V_{OUT} =1.2V, f_{SW} = 400kHz, L=150nH (0.29mΩ), VCC=7V, $T_{AMBIENT} = 25°C$, no heat sink, and no air flow.

The efficiency of an interleaved multiphase IR3553 converter is always higher than that of a single-phase under the same conditions due to the reduced input RMS current and more input/output capacitors.

The measured single-phase IR3553 power loss under the same conditions is provided in Figure 8.

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If any of the application condition, i.e. input voltage, output voltage, switching frequency, VCC MOSFET driver voltage or inductance, is different from those of Figure 8, a set of normalized power loss curves should be used. Obtain the normalizing factors from Figure 10 to Figure 14 for the new application conditions; multiply these factors by the power loss obtained from Figure 8 for the required load current.

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As an example, the power loss calculation procedures under different conditions, V_{IN} =10V, V_{OUT} =1V, f_{SW} = 300kHz, VCC=5V, L=210nH, VCC=5V, I_{OUT} =30A, T_{AMBIENT} = 25°C, no heat sink, and no air flow, are as follows.

- 1) Determine the power loss at 30A under the default test conditions of $V_{IN}=12V$, $V_{OUT}=1.2V$, $f_{SW} = 400kHz$, L=150nH, VCC=7V, $T_{AMBIENT}$ = 25°C, no heat sink, and no air flow. It is 4.7W from Figure 8.
- 2) Determine the input voltage normalizing factor with V_{IN} =10V, which is 1.02 based on the dashed lines in Figure 10.
- 3) Determine the output voltage normalizing factor with $V_{\text{OUT}}=1V$, which is 0.90 based on the dashed lines in Figure 11.
- 4) Determine the switching frequency normalizing factor with f_{SW} = 300kHz, which is 0.99 based on the dashed lines in Figure 12.
- 5) Determine the VCC MOSFET drive voltage normalizing factor with VCC=5V, which is 1.18 based on the dashed lines in Figure 13.
- 6) Determine the inductance normalizing factor with L=210nH, which is 0.94 based on the dashed lines in Figure 14.
- 7) Multiply the power loss under the default conditions by the five normalizing factors to obtain the power loss under the new conditions, which is 4.7W x 1.02 x $0.90 \times 0.99 \times 1.18 \times 0.94 = 4.74W$.

SAFE OPERATING AREA

Figure 9 shows the IR3553 safe operating area with the case temperature controlled at or below 125°C. The test conditions are V_{IN}=12V, V_{OUT}=1.2V, f_{SW} =400kHz, L=150nH (0.29m Ω), VCC=7V, T_{AMBIENT} = 0°C to 90°C, no heat sink, and Airflow = 0LFM / 100LFM / 200LFM / 400LFM.

If any of the application condition, i.e. input voltage, output voltage, switching frequency, VCC MOSFET driver voltage, or inductance is different from those of Figure 9, a set of IR3553 case temperature adjustment curves should be used. Obtain the temperature deltas from Figure 10 to Figure 14 for the new application conditions; sum these deltas and then subtract from the IR3553 case temperature obtained from Figure 9 for the required load current.

- 8) From Figure 9, determine the highest ambient temperature at the required load current under the default conditions, which is 66°C at 30A with 0LFM airflow and the IR3553 case temperature of 125°C.
- 9) Determine the case temperature with $V_{\text{IN}}=10V$, which is +0.6° based on the dashed lines in Figure 10.
- 10) Determine the case temperature with $V_{\text{OUT}}=1V$, which is -3.0° based on the dashed lines in Figure 11.
- 11) Determine the case temperature with $f_{SW} = 300$ kHz, which is -0.4° based on the dashed lines in Figure 12.
- 12) Determine the case temperature with VCC = 5V, which is +5.4° based on the dashed lines in Figure 13.
- 13) Determine the case temperature with L=210nH, which is -1.8° based on the dashed lines in Figure 14.
- 14) Sum the case temperature adjustment from 9) to 13), +0.6° -3.0° -0.4° +5.4° -1.8° = +0.8°. Deduct the delta from the highest ambient temperature in step 8), 66°C $-(+0.8°C) = 65.2°C$.

INDUCTOR CURRENT SENSING CAPACITOR CCS AND RESISTOR RCS

If the IR3553 is used with inductor DCR sensing, care must be taken in the printed circuit board layout to make a Kelvin connection across the inductor DCR. The DC resistance of the inductor is utilized to sense the inductor current. Usually the resistor R_{CS} and capacitor C_{CS} in parallel with the inductor are chosen to match the time constant of the inductor, and therefore the voltage across the capacitor C_{CS} represents the inductor current.

Measure the inductance L and the inductor DC resistance R_L . Pre-select the capacitor C_{CS} and calculate R_{CS} as follows.

$$
R_{CS} = \frac{L/R_L}{C_{CS}}
$$

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INPUT CAPACITORS C_{VIN}

At least two 10uF 1206 ceramic capacitors and one 0.1uF 0402 ceramic capacitor are recommended for decoupling the VIN to PGND connection. The 0.1uF 0402 capacitor should be on the same side of the PCB as the IR3553 and next to the VIN and PGND pins. Adding additional capacitance and use of capacitors with lower ESR and mounted with low inductance routing will improve efficiency and reduce overall system noise, especially in single-phase designs or during high current operation.

BOOTSTRAP CAPACITOR CBOOST

A minimum of 0.22uF 0402 capacitor is required for the bootstrap circuit. A high temperature 0.22uF or greater value 0402 capacitor is recommended. It should be mounted on the same side of the PCB as the IR3553 and as close as possible to the BOOST pin. A low inductance routing of the SW pin connection to the other terminal of the bootstrap capacitor is strongly recommended.

VCC DECOUPLING CAPACITOR C_{VCC}

A 0.1uF to 1uF ceramic decoupling capacitor is required at the VCC pin. It should be mounted on the same side of the PCB as the IR3553 and as close as possible to the VCC and PGND (pin 4). Low inductance routing between the VCC capacitor and the IR3553 pins is strongly recommended.

BODY-BRAKING® FEATURE

The BBRK# pin should be pulled up to VCC if the feature is not used by the PWM controller. Use of a small value resistor or a direct connection to VCC is recommended.

MOUNTING OF HEAT SINKS

Care should be taken in the mounting of heat sinks so as not to short-circuit nearby components. The VCC and Bootstrap capacitors are typically mounted on the same side of the PCB as the IR3553. The mounting height of these capacitors must be considered when selecting their package sizes.

HIGH OUTPUT VOLTAGE DESIGN CONSIDERATIONS

The IR3553 is capable of creating output voltages above the 3.3V recommended maximum output voltage as there are no restrictions inside the IR3553 on the duty cycle applied to the PWM pin. However if the current sense feature is required, the common mode range of the current sense amplifier inputs must be considered. A violation of the current sense input common mode range may cause unexpected IR3553 behavior. Also the output current rating of the device will be reduced as the duty cycle increases. In very high duty cycle applications sufficient time must be provided for replenishment of the Bootstrap capacitor for the control MOSFET drive.

LAYOUT EXAMPLE

Contact International Rectifier for a layout example suitable for your specific application.

METAL AND COMPONENT PLACEMENT

- Lead land width should be equal to nominal part lead width. The minimum lead to lead spacing should be ≥ 0.2 mm to prevent shorting.
- Lead land length should be equal to maximum part lead length +0.15 - 0.3 mm outboard extension and 0 to + 0.05mm inboard extension. The outboard extension ensures a large and visible toe fillet, and the inboard extension will accommodate any part misalignment and ensure a fillet.
- Center pad land length and width should be equal to maximum part pad length and width.
- Only 0.30mm diameter via shall be placed in the area of the power pad lands and connected to power planes to minimize the noise effect on the IC and to improve thermal performance.

Figure 33: Metal and component placement

* Contact International Rectifier to receive an electronic PCB Library file in Cadence Allegro or CAD DXF/DWG format.

SOLDER RESIST

- The solder resist should be pulled away from the metal lead lands by a minimum of 0.06mm. The solder resist miss-alignment is a maximum of 0.05mm and it is recommended that the low power signal lead lands are all Non Solder Mask Defined (NSMD). Therefore pulling the S/R 0.06mm will always ensure NSMD pads.
- The minimum solder resist width is 0.13mm typical.
- At the inside corner of the solder resist where the lead land groups meet, it is recommended to provide a fillet so a solder resist width of \ge 0.17mm remains.
- The dimensions of power land pads, VIN, PGND, TGND and SW, are Non Solder Mask Defined (NSMD). The equivalent PCB layout becomes Solder Mask Defined (SMD) after power shape routing.
- Ensure that the solder resist in-between the lead lands and the pad land is ≥ 0.15 mm due to the high aspect ratio of the solder resist strip separating the lead lands from the pad land.

Figure 34: Solder resist

* Contact International Rectifier to receive an electronic PCB Library file in Cadence Allegro or CAD DXF/DWG format.

STENCIL DESIGN

- The stencil apertures for the lead lands should be approximately 65% to 75% of the area of the lead lands depending on stencil thickness. Reducing the amount of solder deposited will minimize the occurrence of lead shorts. Since for 0.5mm pitch devices the leads are only 0.25mm wide, the stencil apertures should not be made narrower; openings in stencils < 0.25mm wide are difficult to maintain repeatable solder release.
- The low power signal stencil lead land apertures should therefore be shortened in length to keep area ratio of 65% to 75% while centered on lead land.
- The power pads VIN, PGND, TGND and SW, land pad apertures should be approximately 65% to 75% area of solder on the center pad. If too much solder is deposited on the center pad the part will float and the lead lands will be open. Solder paste on large pads is broken down into small sections with a minimum gap of 0.2mm between allowing for out-gassing during solder reflow.
- The maximum length and width of the land pad stencil aperture should be equal to the solder resist opening minus an annular 0.2mm pull back to decrease the incidence of shorting the center land to the lead lands when the part is pushed into the solder paste.

* Contact International Rectifier to receive an electronic PCB Library file in Cadence Allegro or CAD DXF/DWG format.

MARKING INFORMATION

Figure 36: PQFN 4mm x 6mm

PACKAGE INFORMATION

Figure 37: PQFN 4mm x 6mm

Data and specifications subject to change without notice. This product will be designed and qualified for the Industrial market.

Qualification Standards can be found on IR's Web site.

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